

FILED

UNITED STATES COURT OF APPEALS

FOR THE NINTH CIRCUIT

OCT 10 2008

MOLLY C. DWYER, CLERK OF COURT
U.S. COURT OF APPEALS

In re: DYNAMIC RANDOM ACCESS
MEMORY (DRAM) ANTITRUST
LITIGATION,

CENTERPRISE INTERNATIONAL,
LTD,

Plaintiff - Appellant,

v.

MICRON TECHNOLOGY, INC.;
MICRON SEMICONDUCTOR
PRODUCTS INC.; CRUCIAL
TECHNOLOGY, INC.; SAMSUNG
ELECTRONICS CO. LTD.; SAMSUNG
SEMICONDUCTOR, INC.; MOSEL-
VITELIC INCORPORATED; MOSEL-
VITELIC CORPORATION (USA);
INFINEON TECHNOLOGIES AG;
INFFINEON TECHNOLOGIES NORTH
AMERICA CORP. HYNIX
SEMICONDUCTOR AMERICA, INC.;
HYNIX SEMICONDUCTOR AMERICA,
INC.; ELPIDA MEMORY, INC.; ELPIDA
MEMORY (USA INC.; NEC
ELECTRONICS AMERICA, INC.;
NANYA TECHNOLOGY
CORPORATION; NANYA
TECHNOLOGY CORPORATION USA;
WINDBOND ELECTRONICS
CORPORATION; WINDBOND
ELECTRONICS CORPORATION

No. 06-15636

D.C. No. CV-02-01486-PJH

05-03026-PJH

Northern District of California,
San Francisco

MANDATE

AMERICA,

Defendants - Appellees.

The judgment of this Court, entered 08/14/2008, takes effect this date.

This constitutes the formal mandate of this Court issued pursuant to Rule 41(a) of the Federal Rules of Appellate Procedure.

FOR THE COURT:

Molly C. Dwyer
Clerk of Court

By: Theresa Benitez
Deputy Clerk